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Datasheet of TRF3705IRGER - IC QUADRATURE MODULATOR 24VQFN

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TRF3705

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TRF3705 300-MHz to 4-GHz Quadrature Modulator

1 Features

- High Linearity:
 - Output IP3: 30 dBm at 1850 MHz
- Low Output Noise Floor: -160 dBm/Hz
- 78-dBc Single-Carrier WCDMA ACPR at –10-dBm Channel Power
- Unadjusted Carrier Suppression: –40 dBm
- Unadjusted Sideband Suppression: –45 dBc
- Single Supply: 3.3-V Operation
- 1-bit Gain Step Control
- Fast Power-Up/Power-Down

2 Applications

- · Cellular Base Station Transmitter
- CDMA: IS95, UMTS, CDMA2000, TD-SCDMA
- LTE (Long Term Evolution)
- TDMA: GSM, EDGE/UWC-136
- Multicarrier GSM (MC-GSM)
- Wireless MAN Wideband Transceivers

3 Description

The TRF3705 is a low-noise direct quadrature modulator, capable of converting complex modulated signals from baseband or IF directly up to RF. The TRF3705 is a high-performance, superior-linearity device that is ideal to up-convert to RF frequencies of 300 MHz (Note: appropriate matching network is required for optimal performance at 300 MHz) through 4 GHz. The modulator is implemented as a double-balanced mixer.

The RF output block consists of a differential-to-single-ended converter that is capable of driving a single-ended $50-\Omega$ load. The TRF3705 requires a 0.25-V common-mode voltage for optimum linearity performance. The TRF3705 also provides a fast power-down pin that can be used to reduce power dissipation in TDD applications.

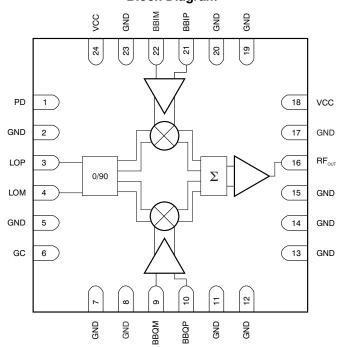
The TRF3705 is available in an RGE-24 VQFN package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TRF3705	VQFN (24)	4.00 mm x 4.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Block Diagram





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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (October 2011) to Revision B	Page
Added the ESD table, Detailed Description, Application and Implementation, Device and Docume Mechanical, Packaging, and Orderable Information	
Added Note 1 to Figure 65	23
• Changed the X-axis label of Figure 75 From: Frequency (MHz) To: LO Power (dBm)	28
Changed Figure 77	
Changes from Original (August 2011) to Revision A	Page
Changed the device From: Preview To: Production	1

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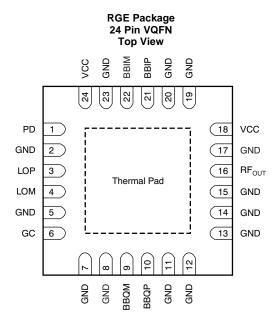




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Pin Configuration and Functions



Pin Functions

	PIN		DECODIOTION
NO.	NAME	I/O	DESCRIPTION
1	PD	I	Power-down digital input (high = device off)
2	GND	I	Ground
3	LOP	I	Local oscillator input
4	LOM	I	Local oscillator input
5	GND	I	Ground
6	GC	I	Gain control digital input (high = high gain)
7	GND	_	Ground or leave unconnected
8	GND	I	Ground
9	BBQM	I	In-quadrature input
10	BBQP	I	In-quadrature input
11	GND	I	Ground
12	GND	I	Ground
13	GND	I	Ground
14	GND	I	Ground
15	GND	I	Ground
16	RF _{OUT}	0	RF output
17	GND	I	Ground
18	VCC	I	Power supply
19	GND	I	Ground
20	GND	I	Ground
21	BBIP	I	In-phase input
22	BBIM	I	In-phase input
23	GND	I	Ground
24	VCC	I	Power supply



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Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

Over operating free-air temperature range (unless otherwise noted).

	MIN	MAX	UNIT
Supply voltage range ⁽²⁾	-0.3	6	V
Digital I/O voltage range	-0.3	V _{CC} + 0.5	V
Operating virtual junction temperature range, T _J	-40	150	°C
Operating ambient temperature range, T _A	-40	85	°C
Storage temperature range, T _{stq}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±4000	
$V_{(ESD)}$	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±250	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CC}	Power-supply voltage	3.15	3.3	3.6	V

Thermal Information

		TRF3705	
	THERMAL METRIC ⁽¹⁾	RGE (VQFN)	UNIT
		24 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	38.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	42.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	16.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	16.6	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	6.6	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

All voltage values are with respect to network ground terminal.



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6.5 Electrical Characteristics: General

Over recommended operating conditions; at power supply = 3.3 V and $T_A = +25 ^{\circ}\text{C}$, unless otherwise noted.

	PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DC PAR	AMETERS				1	
	Total augusts august	T _A = +25°C, device on (PD = low)		306		mA
I _{CC}	Total supply current	$T_A = +25$ °C, device off (PD = high)		35		μA
LO INPU	IT					
	LO low frequency			300		MHz
f_{LO}	LO high frequency			4000		MHz
	LO input power		-10	0	+15	dBm
BASEBA	AND INPUTS					
V _{CM}	I and Q input dc common-mode voltage			0.25	0.5	V
BW	1-dB input frequency bandwidth			1000		MHz
7	Innut importance	Resistance		8		kΩ
Z _I	Input impedance	Parallel capacitance		4.6		pF
POWER	ON/OFF		<u> </u>			
	Turn on time	PD = low to 90% final output power		0.2		μs
	Turn off time	PD = high to initial output power -30 dB		0.2		μs
DIGITAL	INTERFACE				•	
V _{IH}	PD high-level input voltage		2			V
V _{IL}	PD low-level input voltage				0.8	V



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6.6 Electrical Characteristics

Over recommended operating conditions; at power supply = 3.3 V, T_A = +25°C, V_{CM} = 0.25 V; LO Power = 0 dBm, single-ended (LOP); GC set low, V_{IN} BB = 1.0 V_{PP} (diff) in quadrature, and f_{BB} = 5.5 MHz, standard broadband output matching circuit, unless otherwise noted.

	PARAMETERS	TEST CONDITIONS	MIN TYP MAX	UNIT
f _{LO} = 400 l	MHz			
G	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set low	-4.7	dB
G	voltago gam	Output RMS voltage over input I (or Q) RMS voltage, GC set high	-1.9	dB
D	Output power	GC set low	-0.7	dBm
P _{OUT}	Output power	GC set high	2.1	dBm
D4 -ID	0	GC set low	8.5	dBm
P1dB	Output compression point	GC set high	9.1	dBm
ID0	0	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set low	26	dBm
IP3	Output IP3	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high	25.4	dBm
	0	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low	60.2	dBm
IP2	Output IP2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high	61.9	dBm
SBS	Unadjusted sideband suppression		-57.4	dBc
		Measured at LO frequency	-51.6	dBm
CF	Unadjusted carrier feedthrough	Measured at 2 x LO	-50	dBm
	,	Measured at 3 x LO	-49	dBm
	Output noise floor	DC only to BB inputs; 10-MHz offset from LO	-166.7	dBm/Hz
HD2 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$	-67	dBc
HD3 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f _{LO} $\pm (3 \text{ x f}_{BB})$	-64	dBc
f _{LO} = 750 l	MHz			
0	Voltago gain	Output RMS voltage over input I (or Q) RMS voltage, GC set low	0.2	dB
G	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set high	3.0	dB
D	Output power	GC set low	4.2	dBm
P _{OUT}	Output power	GC set high	7	dBm
D4 -ID	0	GC set low	13.3	dBm
P1dB	Output compression point	GC set high	13.9	dBm
IDO.	Outrant IDO	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set low	31.5	dBm
IP3	Output IP3	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high	30.8	dBm
IDO	Outrant IDO	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low	73.6	dBm
IP2	Output IP2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high	80.5	dBm
SBS	Unadjusted sideband suppression		-45.2	dBc
		Measured at LO frequency	-45.7	dBm
CF	Unadjusted carrier feedthrough	Measured at 2 x LO	-46	dBm
	,	Measured at 3 x LO	-53.5	dBm
	Output noise floor	DC only to BB inputs; 10-MHz offset from LO	-159.9	dBm/Hz
HD2 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f _{LO} $\pm (2 \times f_{BB})$	-70	dBc
HD3 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$	-66	dBc

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Electrical Characteristics (continued)

Over recommended operating conditions; at power supply = 3.3 V, $T_A = +25^{\circ}C$, $V_{CM} = 0.25$ V; LO Power = 0 dBm, single-ended (LOP); GC set low, V_{IN} BB = 1.0 V_{PP} (diff) in quadrature, and $f_{BB} = 5.5$ MHz, standard broadband output matching circuit, unless otherwise noted.

	PARAMETERS	TEST CONDITIONS	MIN TYP MAX	UNIT
f _{LO} = 900 I	MHz			
	Voltoro roin	Output RMS voltage over input I (or Q) RMS voltage, GC set low	0.3	dB
G	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set high	3.1	dB
-	0.1.1	GC set low	4.3	dBm
Pout	Output power	GC set high	7.1	dBm
D4 -ID		GC set low	13.2	dBm
P1dB	Output compression point	GC set high	13.7	dBm
IP3	Output ID2	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set low	31.7	dBm
P3	Output IP3	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high	30.9	dBm
	Outset IDO	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low	71.5	dBm
P2	Output IP2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high	75.3	dBm
SBS	Unadjusted sideband suppression		-43.8	dBc
		Measured at LO frequency	-48.5	dBm
CF	Unadjusted carrier feedthrough	Measured at 2 x LO	-53	dBm
		Measured at 3 x LO	-50	dBm
	Output noise floor	DC only to BB inputs; 10-MHz offset from LO	-157.9	dBm/Hz
HD2 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$	-80	dBc
HD3 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$	-65	dBc
f _{LO} = 1840	MHz			
	Malla na main	Output RMS voltage over input I (or Q) RMS voltage, GC set low	-0.1	dB
G	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set high	2.5	dB
_	0.1.1	GC set low	3.9	dBm
Роит	Output power	GC set high	6.5	dBm
24 15		GC set low	13.2	dBm
P1dB	Output compression point	GC set high	13.6	dBm
IDO.	Outset ID0	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set low	32.1	dBm
IP3	Output IP3	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high	30.3	dBm
IDO.	Outset IDO	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low	60.8	dBm
IP2	Output IP2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high	62	dBm
SBS	Unadjusted sideband suppression		-43.4	dBc
		Measured at LO frequency	-42.4	dBm
CF	Unadjusted carrier feedthrough	Measured at 2 x LO	-41	dBm
		Measured at 3 x LO	-53	dBm
	Output noise floor	DC only to BB inputs; 10-MHz offset from LO	-158.8	dBm/Hz
HD2 _{BB}	Baseband harmonics	Measured with \pm 1-MHz tone at 0.5 V _{PP} each at f _{LO} \pm (2 x f _{BB})	-69	dBc
HD3 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$	-80	dBc



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Electrical Characteristics (continued)

Over recommended operating conditions; at power supply = 3.3 V, $T_A = +25$ °C, $V_{CM} = 0.25$ V; LO Power = 0 dBm, singleended (LOP); GC set low, V_{IN} BB = 1.0 V_{PP} (diff) in quadrature, and f_{BB} = 5.5 MHz, standard broadband output matching circuit, unless otherwise noted.

	PARAMETERS	TEST CONDITIONS	MIN TYP MAX	UNIT
_{LO} = 2140	MHz			
^	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set low	0.1	dB
G	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set high	2.9	dB
n	Output nouse	GC set low	4.1	dBm
Роит	Output power	GC set high	6.9	dBm
D4 -ID	0	GC set low	13.1	dBm
P1dB	Output compression point	GC set high	13.5	dBm
IP3	Output IDO	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set low	28.6	dBm
IP3	Output IP3	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high	27.6	dBm
D.O.	0 / / / / / / / / / / / / / / / / / / /	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low	65.5	dBm
P2	Output IP2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high	68.2	dBm
SBS	Unadjusted sideband suppression		-45.6	dBc
		Measured at LO frequency	-39.3	dBm
CF	Unadjusted carrier feedthrough	Measured at 2 x LO	-37	dBm
		Measured at 3 x LO	-46	dBm
	Output noise floor	DC only to BB inputs; 10-MHz offset from LO	-160.0	dBm/H
HD2 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$	-61	dBc
HD3 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$	-60	dBc
f _{LO} = 2600	MHz		,	
		Output RMS voltage over input I (or Q) RMS voltage, GC set low	-0.8	dB
G	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set high	2	dB
	0.1.1	GC set low	3.2	dBm
Роит	Output power	GC set high	5.6	dBm
24 15	0.1.1.1.1.1	GC set low	12.5	dBm
P1dB	Output compression point	GC set high	12.8	dBm
ID0	0.4.4100	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set low	28	dBm
IP3	Output IP3	Ff _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high	27.2	dBm
		Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low	67.9	dBm
IP2	Output IP2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high	66.4	dBm
SBS	Unadjusted sideband suppression		-52.9	dBm
		Measured at LO frequency	-37.8	dBm
CF	Unadjusted carrier feedthrough	Measured at 2 x LO	-41	dBm
	_	Measured at 3 x LO	-42	dBm
	Output noise floor	DC only to BB inputs; 10-MHz offset from LO	-160.6	dBm/H
HD2 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f _{LO} $\pm (2 \text{ x f}_{BB})$	-67	dBc
HD3 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$	-59	dBc

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Electrical Characteristics (continued)

Over recommended operating conditions; at power supply = 3.3 V, $T_A = +25$ °C, $V_{CM} = 0.25$ V; LO Power = 0 dBm, singleended (LOP); GC set low, V_{IN} BB = 1.0 V_{PP} (diff) in quadrature, and f_{BB} = 5.5 MHz, standard broadband output matching circuit, unless otherwise noted.

	PARAMETERS	TEST CONDITIONS	MIN TYP	MAX	UNIT			
f _{LO} = 350	o = 3500 MHz							
0	Vallana nain	Output RMS voltage over input I (or Q) RMS voltage, GC set low	-1		dB			
G	Voltage gain	Output RMS voltage over input I (or Q) RMS voltage, GC set high	1.8		dB			
В	Output	GC set low	3		dBm			
P _{OUT}	Output power	GC set high	5.8		dBm			
חואם	Output compression maint	GC set low	12.1		dBm			
P1dB	Output compression point	GC set high	12.3		dBm			
IP3	Output IP3	f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set low	23.8		dBm			
IP3		f _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high	25.3		dBm			
IDO	Output ID2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low	47.8		dBm			
IP2	Output IP2	Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high	48.6		dBm			
SBS	Unadjusted sideband suppression		-45.2		dBm			
		Measured at LO frequency	-31.6		dBm			
CF	Unadjusted carrier feedthrough	Measured at 2 x LO	-30		dBm			
		Measured at 3 x LO	-53		dBm			
	Output noise floor	DC only to BB inputs; 10-MHz offset from LO	-160.6		dBm/Hz			
HD2 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f _{LO} $\pm (2 \times f_{BB})$	-54		dBc			
HD3 _{BB}	Baseband harmonics	Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f_{LO} $\pm (3 \times f_{BB})$	-50		dBc			

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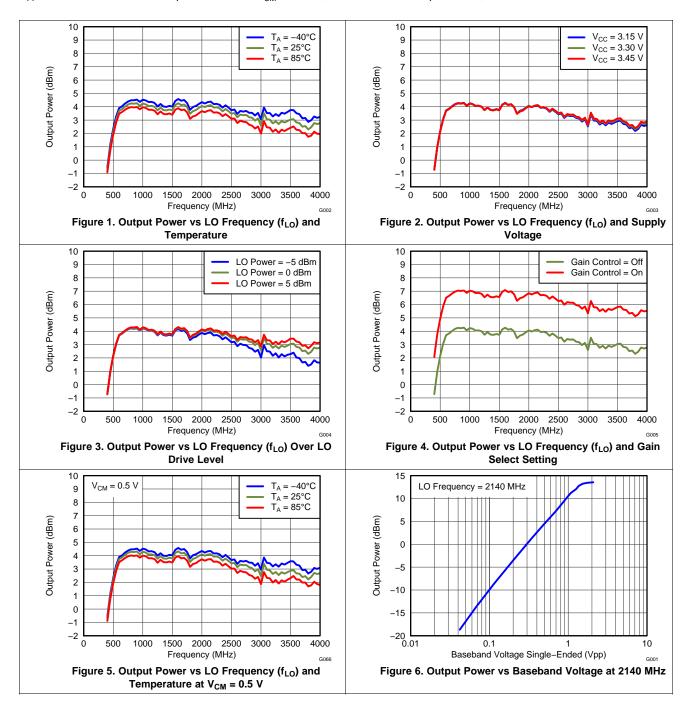
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6.7 Typical Characteristics: Single-Tone Baseband

V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 5.5 MHz; baseband I/Q amplitude = 1- V_{PP} differential sine waves in quadrature with $V_{CM} = 0.25 \text{ V}$; and broadband output match, unless otherwise noted.



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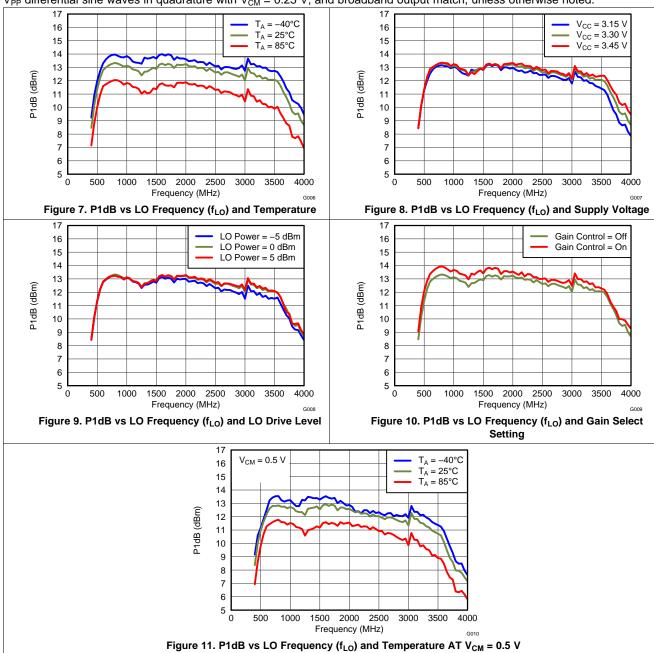
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Typical Characteristics: Single-Tone Baseband (continued)

 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 5.5 MHz; baseband I/Q amplitude = 1- V_{PP} differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.



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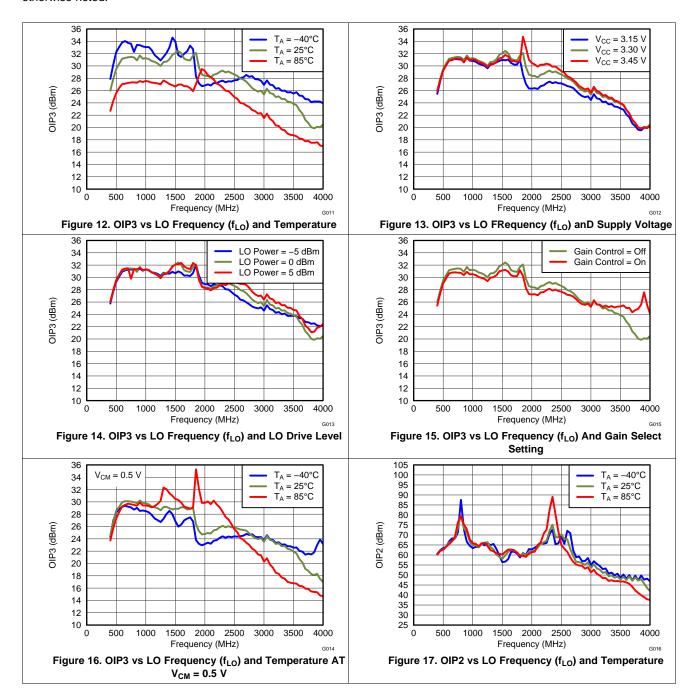
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6.8 Typical Characteristics: Two-Tone Baseband

 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.



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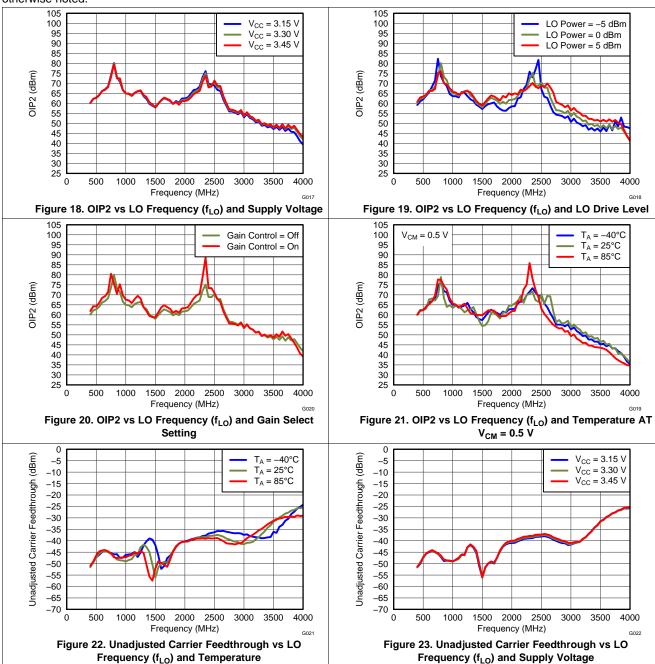
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Typical Characteristics: Two-Tone Baseband (continued)

 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.



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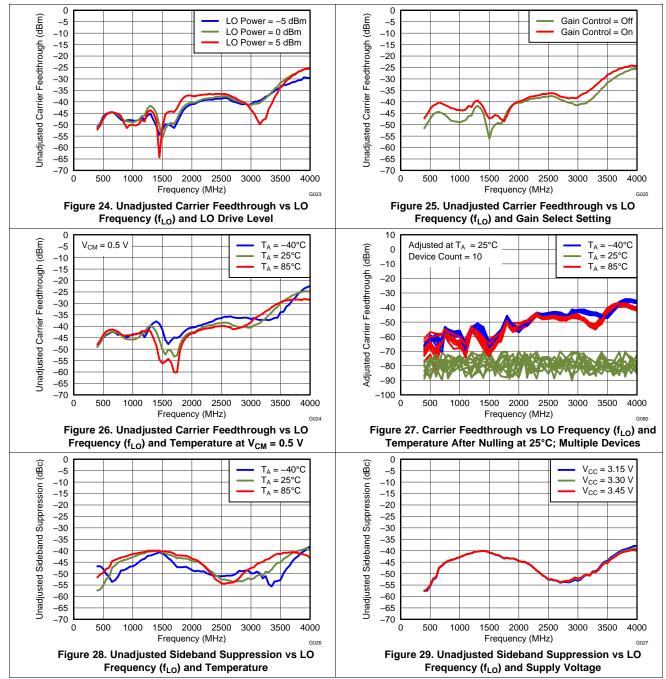
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Typical Characteristics: Two-Tone Baseband (continued)

 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.



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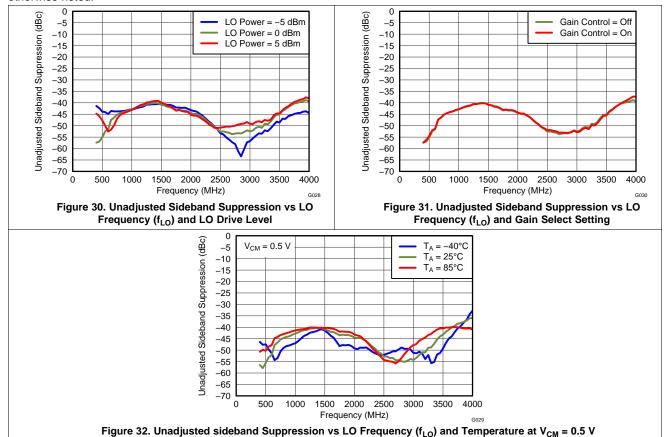


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Typical Characteristics: Two-Tone Baseband (continued)

 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5- V_{PP} /tone differential sine waves in quadrature with $V_{CM} = 0.25 \text{ V}$; and broadband output match, unless otherwise noted.



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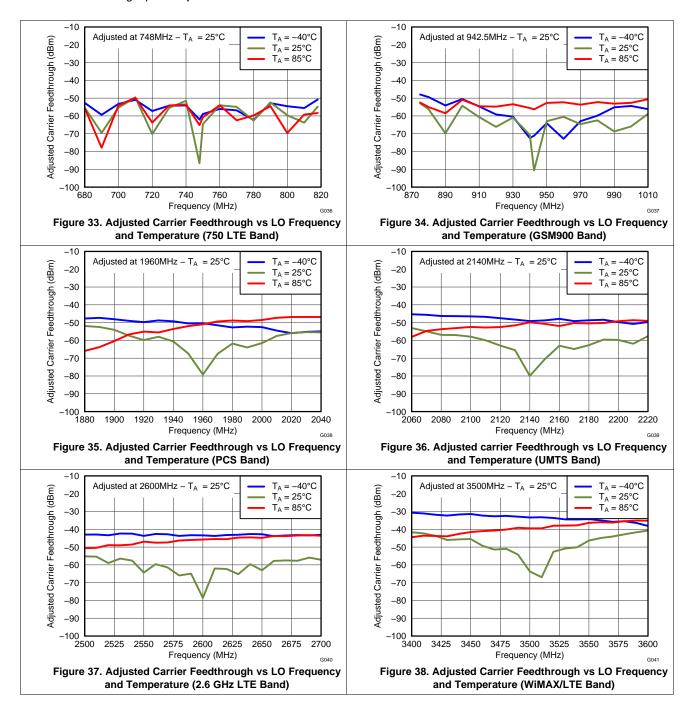
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6.9 Typical Characteristics: Two-Tone Baseband, Mid-Band Calibration

V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted. Single point adjustment mid-band.



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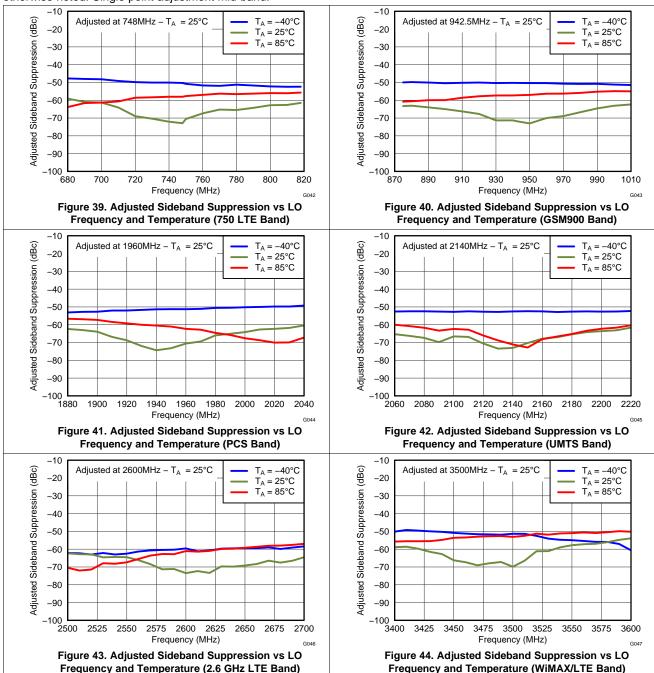


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Typical Characteristics: Two-Tone Baseband, Mid-Band Calibration (continued)

 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted. Single point adjustment mid-band.



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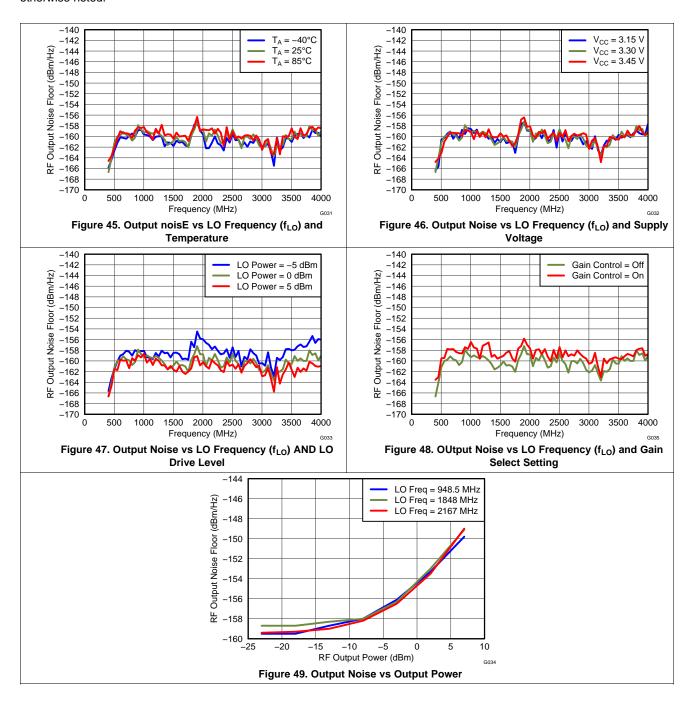
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6.10 Typical Characteristics: No Baseband

 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); and input baseband ports terminated in 50 Ω , unless otherwise noted.



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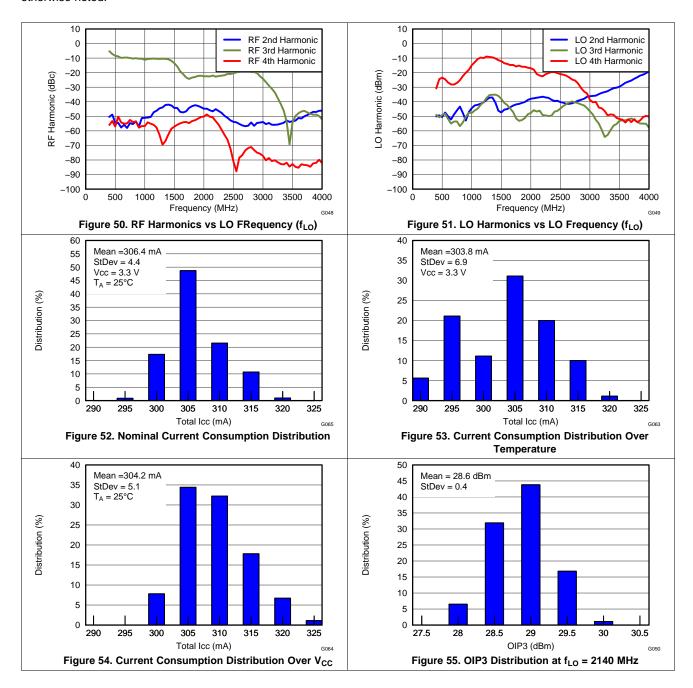


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Typical Characteristics: Two-Tone Baseband

 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5- V_{PP} /tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.



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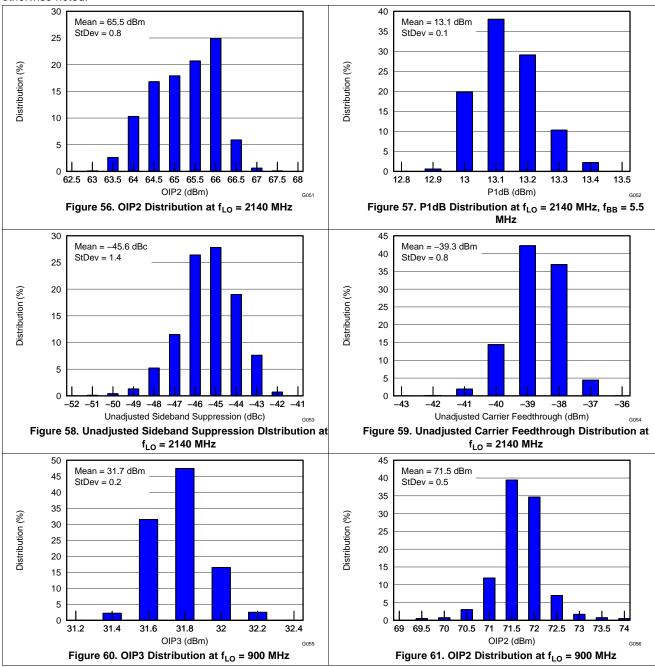
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Typical Characteristics: Two-Tone Baseband (continued)

 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.



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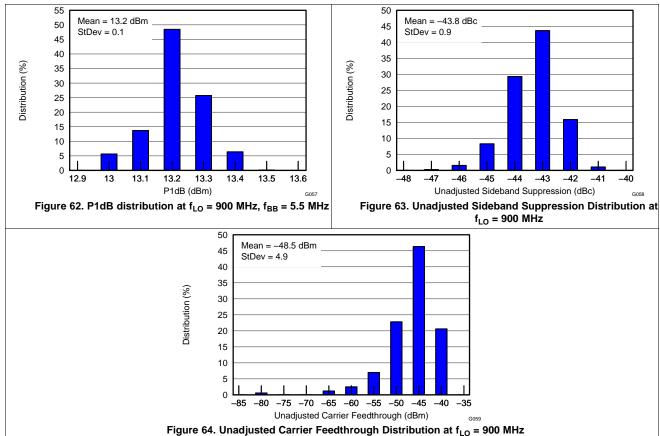
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Typical Characteristics: Two-Tone Baseband (continued)

 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.





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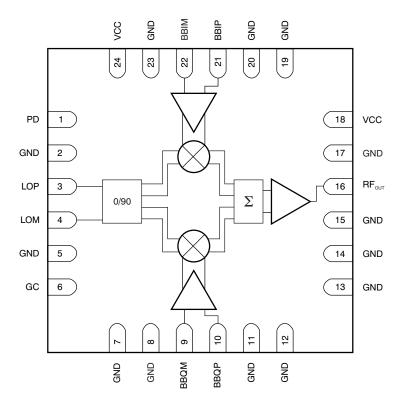
Detailed Description

Overview

TRF3705 is a low-noise direct quadrature modulator with high linearity, capable of converting complex modulated signals from baseband or IF directly to RF. With high-performance and superior-linearity, TRF3705 is an ideal device to up-convert to RF frequencies of 300 MHz through 4 GHz. With appropriate matching network, optimal performance can be obtained. The modulator is implemented as a double-balanced mixer.

TRF3705 has a RF output block which consists of a differential-to-single-ended converter that is capable of directly driving a single-ended 50-Ω load. The TRF3705 requires a 0.25-V common-mode voltage for optimal linearity performance. With a fast power-down pin, TRF3705 can be used to reduce power dissipation in TDD application

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Gain Control Feature

TRF3705 has a specific GC pin which is used for gain control. The GC pin is gain control digital input which is internally pulled down. When driving low or left open, modulator is in low gain mode. With driving high externally, the modulator is in high gain mode. This 1 bit gain step control feature offers a typical 3-dB gain increase in high gain mode. If power optimization is desired, driving this pin low can easily put the modulator into low gain mode.

Device Functional Modes

7.4.1 Power Down Mode

TRF3705 features a PD pin to power down the modulator. The PD pin is internally pulled down. When the powerdown digital input pin is driven high, the device is off. This feature provides a fast power-down which can be used to reduce power dissipation in time division duplexing applications.

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Application and Implementation

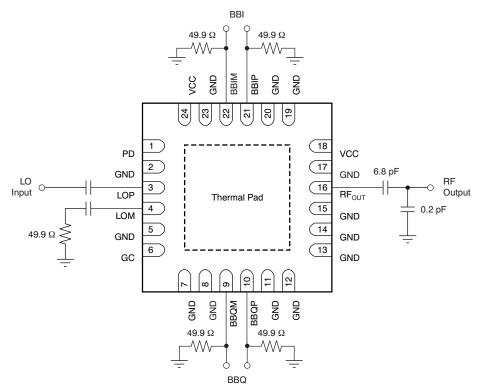
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. Ti's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

TRF3705 is a quadrature modulator for up-converting the in-phase (I) and the quadrature-phase (Q) signals to radio frequency (RF) in the transmit chain. Typically, the device is used between the digital-to-analog converter (DAC) and the RF power amplifier.

8.2 Typical Application



(1) Pin 1 (PD) and Pin 6 (GC) are internally pulled down.

Figure 65. Typical Application Circuit



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Typical Application (continued)

8.2.1 Design Requirements

For this design example, use the parameters shown in Table 1.

Table 1. Pin Termination Requirements and Limitations

NAME	PIN NO	DESCRIPTION
BBQM	9	Base-band in-quadrature input: negative terminal. Input impedance is 8 K Ω //4.6 pF. Optimal linearity is obtained if V $_{CM}$ is 0.25 V. Normally terminated in 50 Ω
BBQP	10	Base-band in-quadrature input: positive terminal. Input impedance is 8 K Ω //4.6 pF. Optimal linearity is obtained if V _{CM} is 0.25 V. Normally terminated in 50 Ω
LOP	3	Local oscillator input: positive terminal. This is preferred port when driving single ended. Normally AC coupled and terminated in 50 Ω
LOM	4	Local oscillator input: negative terminal. When driving LO single-ended, normally AC coupled and terminated in 50 Ω .
RFOUT	16	RF output. Normally using optimal matching circuits to match RF output to 50 Ω . Normally AC coupled.
GC	6	Gain control digital input. Internally pulled down. When driving high, get 3 dB gain increase of RF output.
PD	1	Power down digital input. Internally pulled down. When driving high, the modulator is off.
VCC	18,24	3.3-V power supply. Can be tied together and source from a single clean supply. Each pin should be properly RF bypassed and decoupled.

8.2.2 Detailed Design Procedure

8.2.2.1 Baseband Inputs

The baseband inputs consist of the in-phase signal (I) and the Quadrature-phase signal (Q). The I and Q lines are differential lines that are driven in quadrature. The nominal drive level is 1-V_{PP} differential on each branch.

The baseband lines are nominally biased at 0.25-V common-mode voltage (V_{CM}); however, the device can operate with a V_{CM} in the range of 0 V to 0.5 V. The baseband input lines are normally terminated in 50 Ω , though it is possible to modify this value if necessary to match to an external filter load impedance requirement.

8.2.2.2 LO Input

The LO inputs can be driven either single-ended or differentially. There is no significant performance difference between either option with the exception of the sideband suppression. If driven single-ended, either input can be used, but LOP (pin 3) is recommended for best broadband performance of sideband suppression. When driving in single-ended configuration, simply ac-couple the unused port and terminate in 50 Ω . The comparison of the sideband suppression performance is shown in Figure 71 for driving the LO single-ended from either pin and for driving the LO input differentially.

8.2.2.3 RF Output

The RF output must be ac-coupled and can drive a $50-\Omega$ load. The suggested output match provides the best broadband performance across the frequency range of the device. It is possible to modify the output match to optimize performance within a selected band if needed. The optimized matching circuits are to match the RF output impedances to $50~\Omega$.

Figure 72 shows a slightly better OIP3 performance at the frequency above 1850 MHz with an 0.2-pF matching capacitor.

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8.2.2.4 350-MHz Operation

A different matching circuit, as shown in Figure 66, could also be applied to improve the performance for the frequency from 300 MHz to 400 MHz.

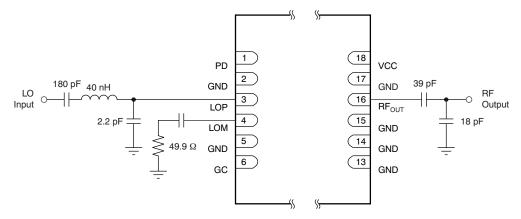


Figure 66. Matching Components for Operation Centered at 350 MHz

Figure 73 and Figure 74 show a slight improvement in OIP3 performance at frequencies above 1850 MHz with an 0.2-pF matching capacitor.

8.2.2.5 DAC to Modulator Interface Network

For optimum linearity and dynamic range, a digital-to-analog converter (DAC) can interface directly with the TRF3705 modulator. It is imperative that the common-mode voltage of the DAC and the modulator baseband inputs be properly maintained. With the proper interface network, the common-mode voltage of the DAC can be translated to the proper common-mode voltage of the modulator. The TRF3705 common-mode voltage is typically 0.25 V, and is ideally suited to interface with the DAC3482/3484 (DAC348x) family because the common-mode voltages of both devices are the same; there is no translation network required. The interface network is shown in Figure 67.

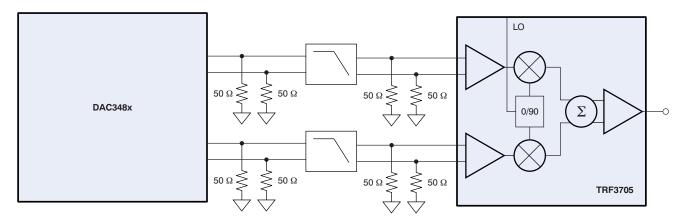


Figure 67. DAC348x Interface with the TRF3705 Modulator

The DAC348x requires a load resistor of 25 Ω per branch to maintain its optimum voltage swing of 1-V_{PP} differential with a 20-mA max current setting. The load of the DAC is separated into two parallel 50-Ω resistors placed on the input and output side of the low-pass filter. This configuration provides the proper resistive load to the DAC while also providing a convenient $50-\Omega$ source and load termination for the filter.

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8.2.2.6 DAC348x with TRF3705 Modulator Performance

The combination of the DAC348x driving the TRF3705 modulator yields excellent system parameters suitable for high-performance applications. As an example, the following sections illustrate the typical modulated adjacent channel power ratio (ACPR) for common telecom standards and bands. These measurements were taken on the DAC348x evaluation board.

8.2.2.6.1 WCDMA

The adjacent channel power ratio (ACPR) performance using a single-carrier WCDMA signal in the UMTS band is shown in Figure 68.

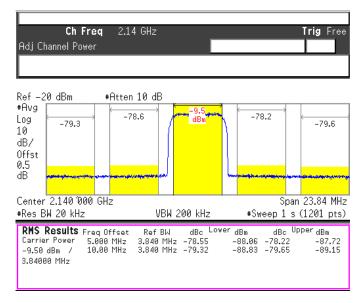


Figure 68. Single-Carrier WCDMA ACPR, IF = 30 MHz, LO Frequency = 2110 MHz

A marginal improvement in OIP3 and output noise performance can be observed by increasing the LO drive power, resulting in slightly improved ACPR performance. The ACPR performance versus LO drive level is plotted in Figure 75 across common frequencies to illustrate the amount of improvement that is possible.



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8.2.2.6.2 LTE

ACPR performance using a 10 MHz LTE signal in the 700-MHz band is shown in Figure 69.

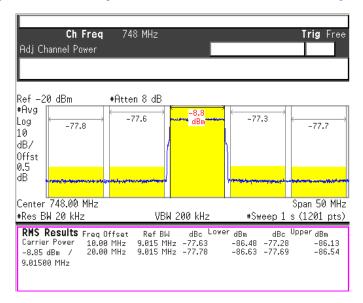


Figure 69. 10 MHz LTE ACPR, IF = 30 MHz, LO Frequency = 718 MHz

8.2.2.6.3 MC-GSM

ACPR performance using a four-carrier MC-GSM signal in the 1800-MHz band is shown in Figure 70.

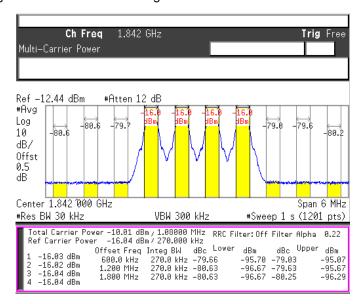


Figure 70. Four-Carrier MC-GSM, IF = 30 MHz ACPR, LO Frequency = 1812 MHz

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8.2.3 Application Curves

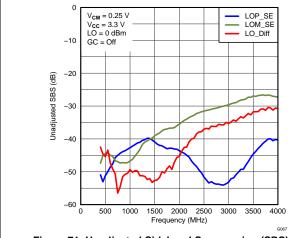


Figure 71. Unadjusted Sideband Suppression (SBS) vs LO **Drive Options**

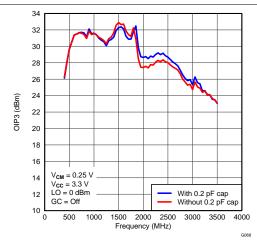


Figure 72. OIP3 with and without a Shunt 0.2-pF Matching Capacitor at the RF Port

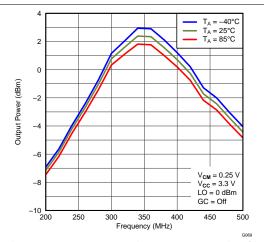


Figure 73. Output Power with 350-MHz Matching Circuit

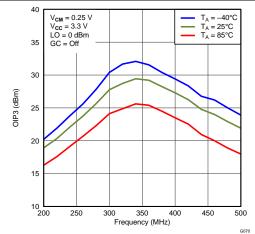


Figure 74. OIP3 with 350-MHz Matching Circuit

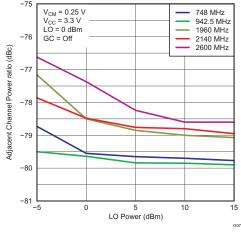


Figure 75. Single-Carrier WCDMA ACPR Performance vs LO Power

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9 Power Supply Recommendations

The TRF3705 is powered by supplying a nominal 3.3 V to pins 18 and 24. These supplies can be tied together and sourced from a single clean supply. Proper RF bypassing should be placed close to each power supply pin.

Ground pin connections should have at least one ground via close to each ground pin to minimize ground inductance. The PowerPADTM must be tied to ground, preferably with the recommended ground via pattern to provide a good thermal conduction path to the alternate side of the board and to provide a good RF ground for the device. (Refer to *Layout Guidelines* for additional information.)

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10 Layout

Populated RoHS-compliant evaluation boards are available for testing the TRF3705 as a stand-alone device. Contact your local TI representative for information on ordering these evaluation modules, or see the TRF3705 product folder on the TI website. In addition, the TRF3705 can be evaluated with the DAC348x (quad/dual 16-bit, 1.25GSPS) EVM driving the baseband inputs through a seamless interface at 0.25V common-mode voltage.

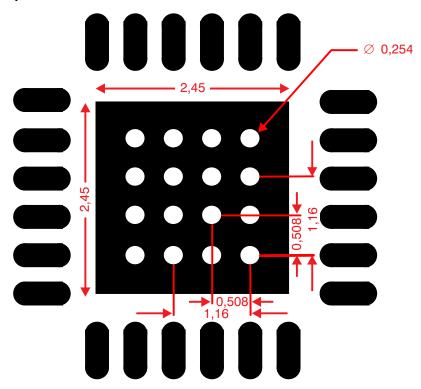
10.1 Layout Guidelines

The TRF3705 device is fitted with a ground slug on the back of the package that must be soldered to the printed circuit board (PCB) ground with adequate ground vias to ensure a good thermal and electrical connection. The recommended via pattern and ground pad dimensions are shown in Figure 76. The recommended via diameter is 10 mils (0.10 in or 0,25 mm). The ground pins of the device can be directly tied to the ground slug pad for a low-inductance path to ground. Additional ground vias may be added if space allows.

Decoupling capacitors at each of the supply pins are strongly recommended. The value of these capacitors should be chosen to provide a low-impedance RF path to ground at the frequency of operation. Typically, the value of these capacitors is approximately 10 pF or lower.

The device exhibits symmetry with respect to the quadrature input paths. It is recommended that the PCB layout maintain this symmetry in order to ensure that the quadrature balance of the device is not impaired. The I/Q input traces should be routed as differential pairs and the respective lengths all kept equal to each other. On the RF traces, maintain proper trace widths to keep the characteristic impedance of the RF traces at a nominal 50 Ω.

10.2 Layout Example



Note: Dimensions are in millimeters (mm).

Figure 76. PCB Ground Via Layout Guide

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11 Device and Documentation Support

11.1 Device Support

11.1.1 Definition of Specifications

11.1.1.1 Carrier Feedthrough

This specification measures the power of the local oscillator component that is present at the output spectrum of the modulator. The performance depends on the dc offset balance within the baseband input lines. Ideally, if all of the baseband lines were perfectly matched, the carrier (that is, the LO) would be naturally suppressed; however, small dc offset imbalances within the device allow some of the LO component to feed through to the output. This parameter is expressed as an absolute power in dBm, and is independent of the RF output power and the injected LO input power.

It is possible to adjust the baseband dc offset balance to suppress the output carrier component. Devices such as the DAC348x DAC family have dc offset adjustment capabilities specifically for this function. The Adjusted Carrier Feedthrough graphs (see Figure 33 through Figure 38) optimize the performance at the center of the band at room temperature. Then, with the adjusted dc offset values held constant, the parameter is measured over the frequency band and across the temperature extremes. The typical performance plots provide an indication of how well the adjusted carrier suppression can be maintained over frequency and temperature with only one calibration point.

11.1.1.2 Sideband Suppression

This specification measures the suppression of the undesired sideband at the output of the modulator relative to the desired sideband. If the amplitude and phase within the I and Q branch of the modulator were perfectly matched, the undesired sideband (or image) would be naturally suppressed. Amplitude and phase imbalance in the I and Q branches result in the increase of the undesired sideband. This parameter is measured in dBc relative to the desired sideband.

It is possible to adjust the relative amplitude and phase balance within the baseband lines to suppress the unwanted sideband. Devices such as the DAC348x DAC family have amplitude and phase adjustment control specifically for this function. The Adjusted Sideband Suppression graphs (refer to Figure 39 through Figure 44) optimize the performance at the center of the band at room temperature. Then, with the adjusted amplitude and phase values held constant, the parameter is measured over the frequency band and across the temperature extremes. The performance plots provide an indication of how well the adjusted sideband suppression can be maintained over frequency and temperature with only one calibration point.

11.1.1.3 Output Noise

The output noise specifies the absolute noise power density that is output from the RF_{OUT} pin (pin 16). This parameter is expressed in dBm/Hz. This parameter, in conjunction with the OIP3 specification, indicates the dynamic range of the device. In general, at high output signal levels the performance is limited by the linearity of the device; at low output levels, on the other hand, the performance is limited by noise. As a result of the higher gain and output power of the TRF3705 compared to earlier devices, it is expected that the noise density is slightly higher as well. With its increased gain and high OIP3 performance, the overall dynamic range of the TRF3705 is maintained at exceptional levels.

11.1.1.4 Definition of Terms

A simulated output spectrum with two tones is shown in Figure 77, with definitions of various terms used in this data sheet.

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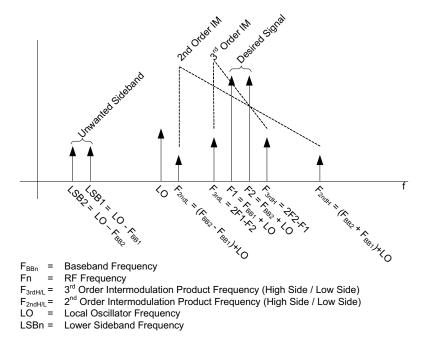


Figure 77. Graphical Illustration of Common Terms

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of

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Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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11.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



Datasheet of TRF3705IRGER - IC QUADRATURE MODULATOR 24VQFN

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PACKAGE OPTION ADDENDUM

15-Jan-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins Pac	ckage	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TRF3705IRGER	ACTIVE	VQFN	RGE	24 3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TRF3705 IRGE	Samples
TRF3705IRGET	ACTIVE	VQFN	RGE	24 2	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TRF3705 IRGE	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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Addendum-Page 1



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PACKAGE OPTION ADDENDUM

INSTRUMENTS

15-Jan-2015

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

Addendum-Page 2

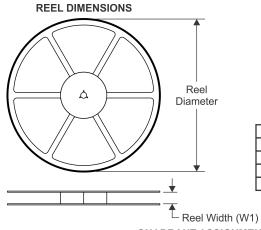
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PACKAGE MATERIALS INFORMATION

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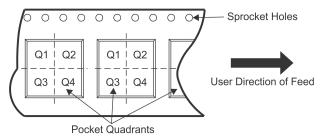
TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity AO

A0	
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRF3705IRGER	VQFN	RGE	24	3000	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2
TRF3705IRGET	VQFN	RGE	24	250	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2

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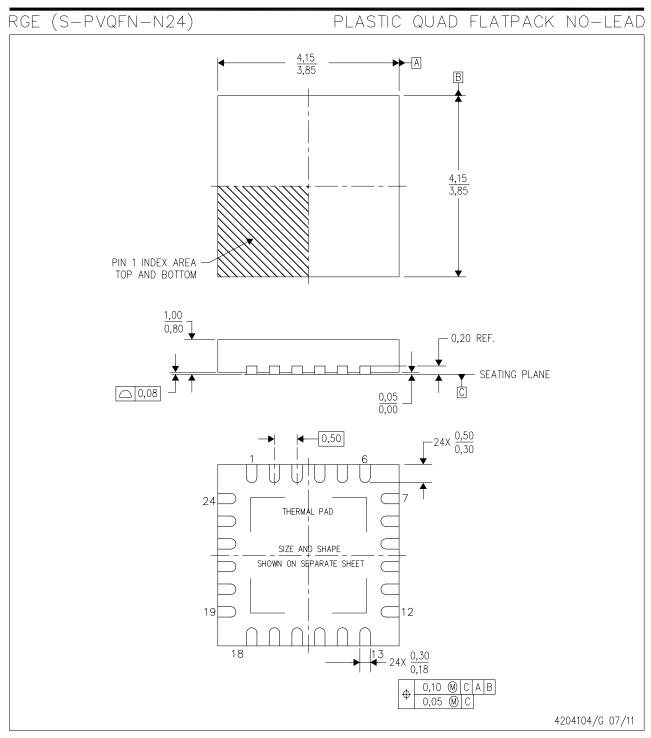


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRF3705IRGER	VQFN	RGE	24	3000	367.0	367.0	38.0
TRF3705IRGET	VQFN	RGE	24	250	338.1	338.1	20.6



MECHANICAL DATA



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-220.





THERMAL PAD MECHANICAL DATA

RGE (S-PVQFN-N24)

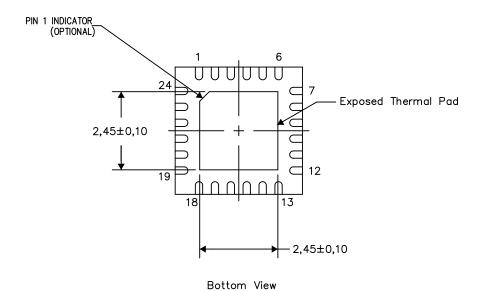
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206344-3/AK 08/15

NOTES: A. All linear dimensions are in millimeters

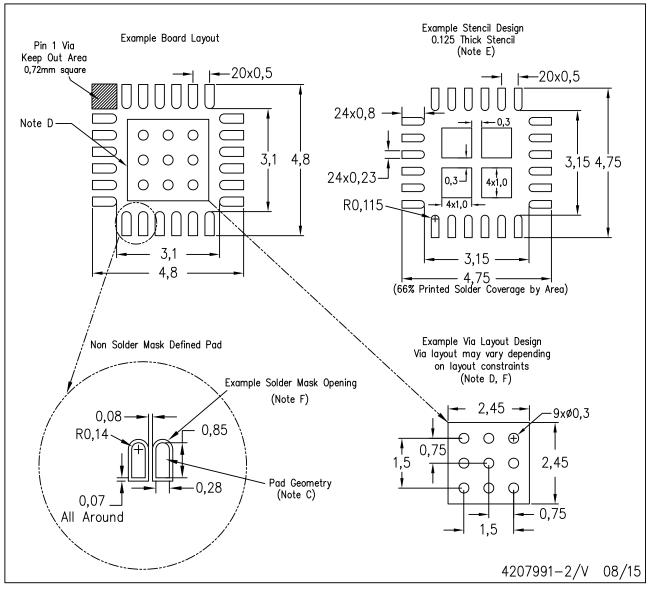




LAND PATTERN DATA

RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.





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